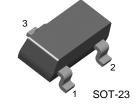


### **KSC2223**

### **High Frequency Amplifier**

- Very small size to assure good space factor in Hybrid IC applications
- f<sub>T</sub>=600MHz (TYP) at I<sub>C</sub>=1mA
  C<sub>ob</sub>=1pF (TYP) at V<sub>CB</sub>=6V
- NF=3dB (TYP) at f=100MHz



1. Base 2. Emitter 3. Collector

## **NPN Epitaxial Silicon Transistor**

## **Absolute Maximum Ratings** $T_a$ =25°C unless otherwise noted

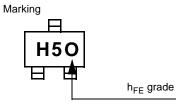
| Symbol           | Parameter                   | Value     | Units |
|------------------|-----------------------------|-----------|-------|
| V <sub>CBO</sub> | Collector-Base Voltage      | 30        | V     |
| V <sub>CEO</sub> | Collector-Emitter Voltage   | 20        | V     |
| V <sub>EBO</sub> | Emitter-Base Voltage        | 4         | V     |
| I <sub>C</sub>   | Collector Current           | 20        | mA    |
| P <sub>C</sub>   | Collector Power Dissipation | 150       | mW    |
| T <sub>J</sub>   | Junction Temperature        | 150       | °C    |
| T <sub>STG</sub> | Storage Temperature         | -55 ~ 150 | °C    |

### Electrical Characteristics T<sub>a</sub>=25°C unless otherwise noted

| Symbol                | Parameter                            | Test Condition   | Min. | Тур. | Max. | Units |
|-----------------------|--------------------------------------|--|------|------|------|-------|
| I <sub>CBO</sub>      | Collector Cut-off Current            | $V_{CB=}30V$ , $I_{E}=0$                                     |      |      | 0.1  | μΑ    |
| h <sub>FE</sub>       | DC Current Gain                      | V <sub>CE</sub> =6V, I <sub>C</sub> =1mA                     | 40   | 90   | 180  |       |
| V <sub>CE</sub> (sat) | Collector Emitter Saturation Voltage | I <sub>C</sub> =10mA, I <sub>B</sub> =1mA                    |      | 0.1  | 0.3  | V     |
| C <sub>ob</sub>       | Output Capacitance                   | $V_{CB}=6V$ , $I_{E}=0$ , $f=1MHz$                           |      | 1    |      | pF    |
| f <sub>T</sub>        | Current Gain Bandwidth Product       | V <sub>CE</sub> =6V, I <sub>C</sub> =1mA                     | 400  | 600  |      | MHz   |
| C <sub>c-rbb</sub>    | Time Constant                        | V <sub>CB</sub> =6V, I <sub>C</sub> =1mA<br>f=31.9MHz        |      | 12   |      | ps    |
| NF                    | Noise Figure                         | $V_{CE}$ =6V, $I_{C}$ =1mA<br>f=100MHz, $R_{S}$ =50 $\Omega$ |      | 3    |      | dB    |

### **h**<sub>FE</sub> Classification

| h <sub>FE</sub> 40 ~ 80 60 ~ 120 | 90 ~ 180 |
|----------------------------------|----------|



## **Typical Characteristics**

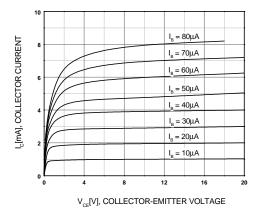


Figure 1. Static Characteristic

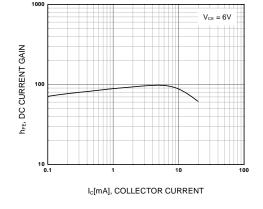


Figure 2. DC current Gain 1

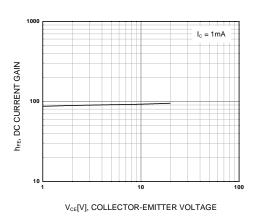


Figure 3. DC current Gain 2

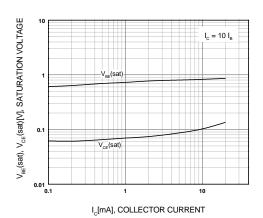


Figure 4. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

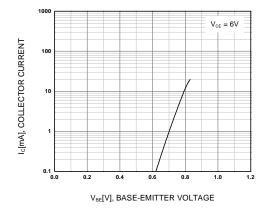


Figure 5. Base-Emitter On Voltage

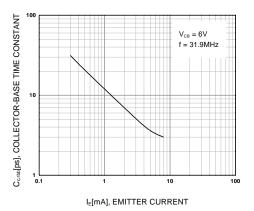


Figure 6. Collector-Base Time Constant

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# Typical Characteristics (Continued)

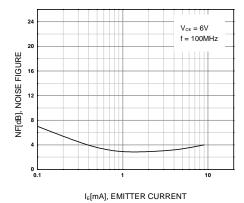


Figure 7. Noise Figure

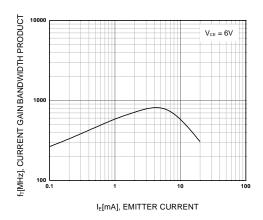


Figure 8. Current Gain Bandwidth Product

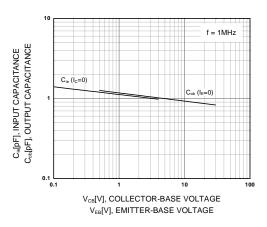


Figure 9. Input and Output Capacitance

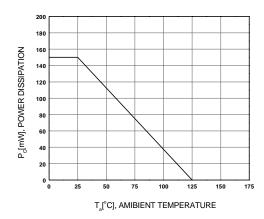
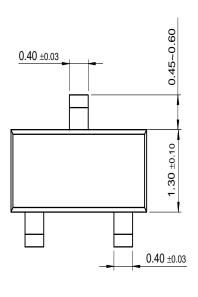
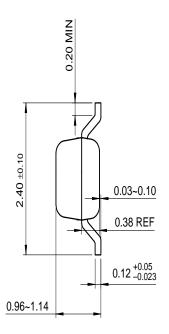


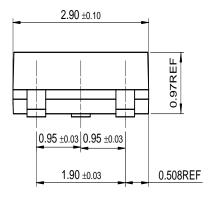
Figure 10. Power Derating

## **Package Dimensions**

## **SOT-23**







Dimensions in Millimeters

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| CoolFET™             | FASTr™              | MicroFET™              | PowerTrench <sup>®</sup> | SuperSOT™-6           |
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| EcoSPARK™            | GTO™                | MSX™                   | QT Optoelectronics™      | TinyLogic™            |
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| EnSigna™             | $I^2C^{TM}$         | $OCX^{TM}$             | RapidConfigure™          | UHC™                  |
| Across the board.    | Around the world.™  | OCXPro™                | RapidConnect™            | UltraFET <sup>®</sup> |
| The Power Franci     | hise™               | OPTOLOGIC <sup>®</sup> | SILENT SWITCHER®         | VCX <sup>TM</sup>     |
| Programmable Ad      | ctive Droop™        | OPTOPLANAR™            | SMART START™             |                       |

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